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Paper Title list.

paper ID	Full Manuscript	eCopyright Identifier	Paper Title
101	101.pdf	101	A Low-Dropout Linear Regulator with Nested Miller Compensation in 65-nm SOI CMOS.....1
105	105.pdf	105	A K-to-Ka Band Ultra Wideband Power Amplifier in 180-nm SiGe Technology.....5
106	106.pdf	106	A 1MHz, 93.7% Peak Efficiency, Heterogenous GaN/BCD 48-to-3.3V~5V DC-DC Buck Converter.....9
109	109.pdf	109	Enhanced FeFET Performance for Energy Efficient Neuromorphic Computing at Cryogenic Conditions.....13
111	111.pdf	111	A Unified TRNG And PUF Module Based On Threshold Switching Array.....16
112	112.pdf	112	Reversible transition of volatile to non-volatile resistive switching in Cu/SiNx/ZnO/Pt memristor.....19
113	113.pdf	113	A 0.007 mm ² , 0.1-4 GHz SDR RF Front-End for Wireless Sensor Networks in 65nm CMOS.....22
114	114.pdf	114	A System-in-package for Smart Microphone with Ultra-low Power AI co-processor.....26
115	115.pdf	115	Optimization of Geometrical Parameters of Metal Plates for Isolation Capacitors.....31
116	116.pdf	116	Memorable Logic Gate Based on Field Effect Oxide Resistive Switching Devices.....35
118	118.pdf	118	Ultrafast self-rectifying memristors for advanced in-memory computing.....38
119	119.pdf	119	3D Phase Field Simulation and Variability Analysis of Polycrystalline Ferroelectric Memories.....41
120	120.pdf	120	NbOx Selector with TiOy Interlayer for Improved Performance Featuring On-Off ratio >500, Selectivity >500 and Switching Speed <70ns.....45
121	121.pdf	121	Behavioural Modelling of Fractional-N All Digital Phase-locked Loop For Low-Power Applications.....47
123	123.pdf	123	Design of a General-Purpose, Compact, Operational Amplifier for Analog VLSI Cell Libraries.....51
126	126.pdf	126	A Failure Analysis Framework For Ferroelectric Field-Effect Transistor Memory.....55

127	127.pdf	127	Radiation Induced Degradation of Charge-trap (CT) 3D-NAND Flash Memory.....59
128	128.pdf	128	Enhanced External Quantum Efficiency in Silicon Avalanche Photodiode With Inverted Pyramidal Structure Surface Texturing.....63
129	129.pdf	129	Advanced FD-SOI engineered substrates for automotive radar applications.....65
131	131.pdf	131	An Ultra-Low Power CMOS Low Noise Amplifier Using Self-Forward Body Biasing for 2.4 GHz Wireless Communication.....69
132	132.pdf	132	An Ultra-Low Power Low-IF BLE Receiver for IoT Applications.....73
134	134.pdf	134	A 2.4 GHz High Efficiency Wideband Power Amplifier in 28-nm CMOS Process.....77
135	135.pdf	135	A 2.4 GHz Fully Integrated Highly Linear Class E Power Amplifier in 28-nm CMOS.....80
137	137.pdf	137	A Wide Input Range RF Energy Harvester With Low Leakage Current for Far-Field Wireless Power Transfer in 28nm CMOS Technology.....84
140	140.pdf	140	A Novel Low-Energy Memristor with Coexisting Synaptic and Neuronal Behaviours.....88
141	141.pdf	141	One Ferroelectric Field-Effect Transistor and one Capacitor Ternary Content-Addressable Memory Based on Charge Domain Sensing Mechanism.....91
142	142.pdf	142	Integration of Volume Change Liner Stressor on Ferroelectric Capacitors and FeFETs: Simulation and Electrical Characterization.....94
143	143.pdf	143	Simulation and Analysis of GaN MIS-HEMT Based Optimized Bootstrap Comparator Applied to DC-DC Buck Converter Feedback Loop.....98
144	144.pdf	144	Impact of Gate Structure on the Electrophysiology Detection Behaviors for SOI Ion-Sensitive FETs.....102
148	148.pdf	148	Deep Insight of Self-heating Effect Induced Hot Carrier Reliability Improvement in LDMOS Devices.....105
149	149.pdf	149	Interface Engineering for Performance and Reliability Optimization of Hf _{0.5} Zr _{0.5} O ₂ FeFETs: Device Integration and Electrical Characterization.....109
150	150.pdf	150	Revealing the Scattering Mechanisms of Mobility Degradation in Ultrathin Body SOI pMOSFETs.....113
152	152.pdf	152	Design of a Broadband GaN-on-Si Monolithic Millimeter-Wave Transceiver Multi-Function Chip.....117

153	153.pdf	153	A Comparative Study of Electrodes for Ferroelectric Capacitor Based Memory.....121
154	154.pdf	154	Research on Switching Characteristics and Pulse Control of Wide Bandgap Semiconductor SiC-based Memristor.....124
155	155.pdf	155	Why does AlScN appear to be the best choice for IIIA-VA-based wurtzite ferroelectrics?.....127
156	156.pdf	156	Exploration of Synaptic Plasticity in Memristor based Wurtzite Ferroelectric Material.....131
157	157.pdf	157	A low-power SAR ADC with different weighted capacitor array by using merge and split switching technique.....134
160	160.pdf	160	Substrate Coupling in SOI Technology: An Electromagnetic Study for RF Integrated Circuit Design & Manufacturing...138
162	162.pdf	162	Managing Crosstalk in multi-GHz Front Side Clock for Back Side Power enabled Sub-2nm 2D/3D ICs.....143
163	163.pdf	163	A Transient-Enhanced Low-Dropout Regulator Design With Embedded Voltage Reference in 55-nm CMOS Technology.....147
165	165.pdf	165	Static characteristics and avalanche robustness of SiC MOSFET with P-well surface doping investigation.....151
166	166.pdf	166	Impact of Passivation on Thermal Stability of AlGaN/GaN HEMTs Under High-Temperature Annealing.....155
167	167.pdf	167	An Energy-Efficient Low-Voltage SRAM-based Charge Recovery Logic Near-Memory-Computing Macro for Edge Computing.....159
168	168.pdf	168	6-inch GaN-on-Si Fabrication Technologies for Monolithic Microwave Integrated Circuits (MMICs).....163
169	169.pdf	169	Memcapacitor with High Switching Ratio and Tunable Synaptic Plasticity.....167
170	170.pdf	170	Low-Voltage Low-Power Scalable Voltage Reference.....170
171	171.pdf	171	120 nm GaN HEMTs on a Si Substrate for Mm-Wave Mobile SoC Applications.....174
172	172.pdf	172	What you need to know for growth of AlScN Thin Film via Atomic Layer Deposition?.....178
173	173.pdf	173	A Ferroelectric Reconfigurable Memory with Excitatory and Inhibitory Synaptic Responses.....182
174	174.pdf	174	Temperature Dependence in Coercive Field of Ferroelectric AlScN Integrated on Si Substrate.....186
175	175.pdf	175	GaN Surface Acoustic Wave Resonators on Si Substrate for RF Applications.....190

176	176.pdf	176	Strong Polarization AlN/GaN/Si Heterojunction MIS-HEMT for Mm-Wave Low-Voltage Terminal Applications.....194
177	177.pdf	177	Crosstalk reduction in a RGBW CFA image sensor.....197
178	178.pdf	178	Au-free multi-layer Ti/Al Ohmic contacts for AlGaN/GaN HEMTs.....200
179	179.pdf	179	GaN-on-Si Solid-State Electronic Devices for Multipliers Applications.....204
180	180.pdf	180	Auto Power-SOI: Shaping the Future of Battery Monitoring Technology.....208
181	181.pdf	181	CMOS Based Spiking-Time Dependent Plasticity Circuit and Simple Image Classification.....213